# 2SD1480

### Silicon NPN triple diffusion planar type

For power amplification

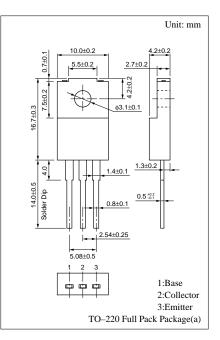
Complementary to 2SB1052

#### Features

- High forward current transfer ratio h<sub>FE</sub> which has satisfactory linearity
- Low collector to emitter saturation voltage V<sub>CE(sat)</sub>
- Full-pack package which can be installed to the heat sink with one screw

Parameter		Symbol	Ratings	Unit		
Collector to base voltage		V <sub>CBO</sub>	60	V		
Collector to emitter voltage		V <sub>CEO</sub>	60	V		
Emitter to base voltage		V <sub>EBO</sub>	6	V		
Peak collector current		I <sub>CP</sub>	4	А		
Collector current		I <sub>C</sub>	2	А		
Collector power	T <sub>C</sub> =25°C	P	25	W		
dissipation	Ta=25°C	P <sub>C</sub>	2			
Junction temperature		Tj	150	°C		
Storage temperature		T <sub>stg</sub>	-55 to +150	°C		

#### Absolute Maximum Ratings $(T_c=25^{\circ}C)$



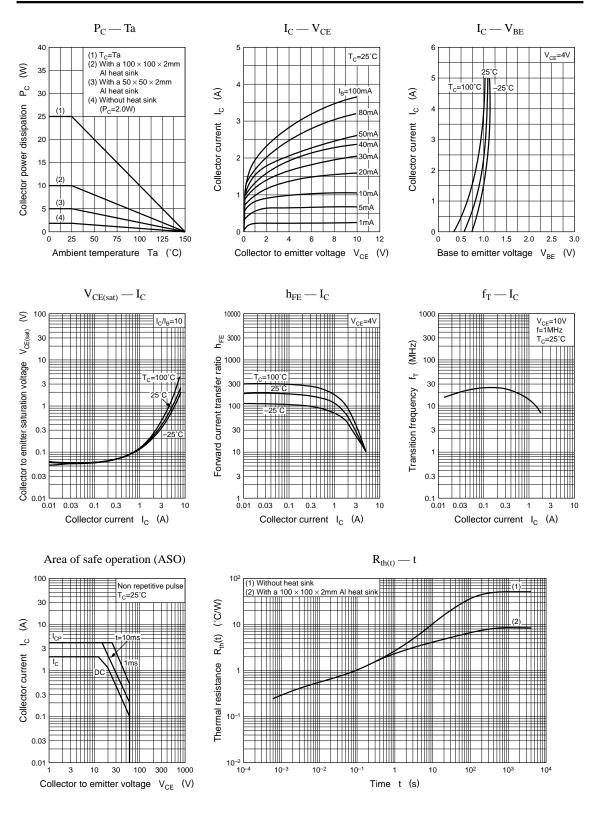
#### Electrical Characteristics (T<sub>C</sub>=25°C)

Parameter	Symbol	Conditions	min	typ	max	Unit
Collector cutoff current	I <sub>CES</sub>	$V_{CE} = 60V, V_{BE} = 0$			200	μA
	I <sub>CEO</sub>	$V_{CE} = 30V, I_B = 0$			300	μA
Emitter cutoff current	I <sub>EBO</sub>	$V_{EB} = 6V, I_C = 0$			1	mA
Collector to emitter voltage	V <sub>CEO</sub>	$I_{\rm C} = 30 {\rm mA}, I_{\rm B} = 0$	60			v
Forward current transfer ratio	h <sub>FE1</sub>	$V_{CE} = 4V, I_{C} = 0.1A$	35			
	h <sub>FE2</sub> *	$V_{CE} = 4V, I_{C} = 1A$	70		250	
Base to emitter voltage	V <sub>BE</sub>	$V_{CE} = 4V, I_C = 1A$			1.2	v
Collector to emitter saturation voltage	V <sub>CE(sat)</sub>	$I_{\rm C} = 2A, I_{\rm B} = 0.2A$			2	v
Transition frequency	f <sub>T</sub>	$V_{CE} = 10V, I_C = 0.5A, f = 1MHz$		20		MHz
Turn-on time	t <sub>on</sub>	$I_{C} = 1A, I_{B1} = 0.1A, I_{B2} = -0.1A,$		0.2		μs
Storage time	t <sub>stg</sub>			3.5		μs
Fall time	t <sub>f</sub>	$V_{\rm CC} = 50 V$		0.7		μs

\*hFE2 Rank classification

Rank	Q	Р
h <sub>FE2</sub>	70 to 150	120 to 250

#### **Power Transistors**



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